



Product Overview

2SB1121: Bipolar Transistor, -25V, -2A, Low VCE(sat) PNP Single PCP

For complete documentation, see the [data sheet](#)

Product Description

2SB1121 is Bipolar Transistor, -25V, -2A, Low VCE(sat) PNP Single PCP.

Features

- Adoption of FBET, MBIT processes
- Low collector-to-emitter saturation voltage
- Large current capacity and wide ASO
- Fast switching speed
- Ultrasmall size making it easy to provide high-density, small-sized hybrid IC's

Part Electrical Specifications

| Product | Compliance | Status | Polarity | I _C Continuous (A) | V _{(BR)CEO} Min (V) | h _{FE} Min | h _{FE} Max | f _T Min (MHz) | P _{TM} Max (W) | Package Type |
|---------------|------------|--------|----------|-------------------------------|------------------------------|---------------------|---------------------|--------------------------|-------------------------|----------------|
| 2SB1121S-TD-E | Pb-free | Active | PNP | 2 | 25 | 140 | 280 | 150 | 1.3 | SOT-89 / PCP-1 |
| 2SB1121T-TD-E | Pb-free | Active | PNP | 2 | 25 | 200 | 400 | 150 | 1.3 | SOT-89 / PCP-1 |

For more information please contact your local sales support at www.onsemi.com

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